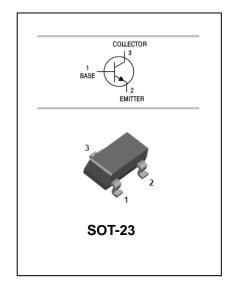


### **S8050**

#### **FEATURES**

- High Collector Current.(I<sub>C</sub>= 500mA).
- Complementary To S8550.
- Excellent H<sub>FE</sub> Linearity.
- High total power dissipation.(P<sub>C</sub>=300mW).



#### **APPLICATIONS**

High Collector Current..

#### ORDERING INFORMATION

Type No.	Marking	Package Code	
S8050	J3Y	SOT-23	

### MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current -Continuous	500	mA
Pc	Collector Dissipation	300	mW
$T_{j,}T_{stg}$	Junction and Storage Temperature	-55 to +150	${\mathbb C}$



**S8050** 

### ELECTRICAL CHARACTERISTICS @ Ta=25℃ unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100μΑ,I <sub>E</sub> =0	40			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =0.1mA,I <sub>B</sub> =0	25			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100μA,I <sub>C</sub> =0	5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =40V,I <sub>E</sub> =0			0.1	μΑ
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =20V,I <sub>B</sub> =0			0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V,I <sub>C</sub> =0			0.1	μΑ
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =1V,I <sub>C</sub> =50mA V <sub>CE</sub> =1V,I <sub>C</sub> =500mA	120 50		350	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> = 50mA			0.6	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> = 50mA			1.2	٧
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =6V, I <sub>C</sub> = 20mA f=30MHz	150			MHz

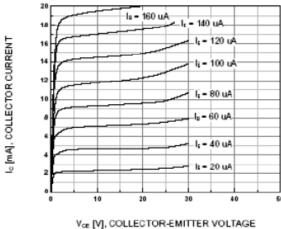
### CLASSIFICATION OF $h_{\text{FE}(1)}$

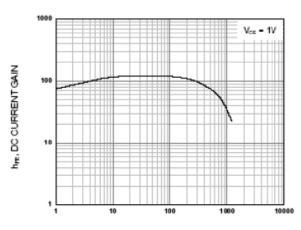
Rank	L	Н
Range	120-200	200-350



#### S8050

### TYPICAL CHARACTERISTICS @ Ta=25℃ unless otherwise specified





Ic [mA], COLLECTOR CURRENT

Figure 2. DC current Gain

Figure 1. Static Characteristic

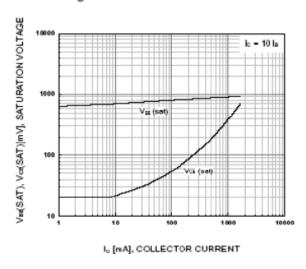


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

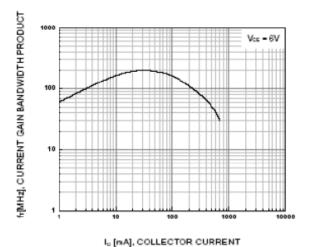


Figure 4. Current Gain Bandwidth Product

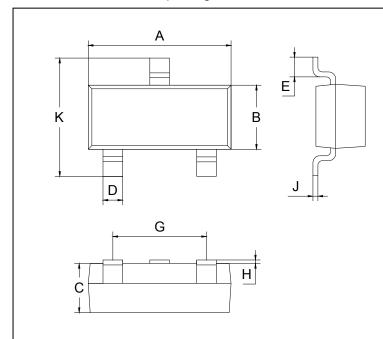


**S8050** 

### PACKAGE OUTLINE

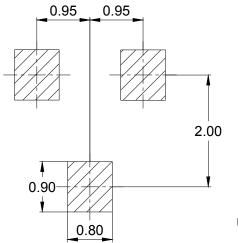
Plastic surface mounted package

SOT-23



SOT-23			
Dim	Min	Max	
Α	2.70	3.10	
В	1.10	1.50	
С	1.0 Typical		
D	0.4 Typical		
Е	0.35	0.48	
G	1.80	2.00	
Н	0.02	0.1	
J	0.1 Typical		
K	2.20	2.60	
All Dimensions in mm			

### **SOLDERING FOOTPRINT**



Unit: mm

#### PACKAGE INFORMATION

Device	Package	Shipping
S8050	SOT-23	3000/Tape&Reel